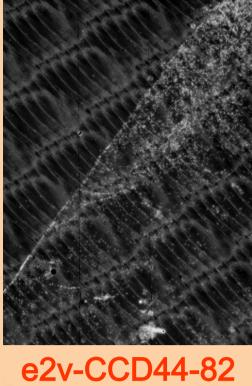
CCD UV QE improvement

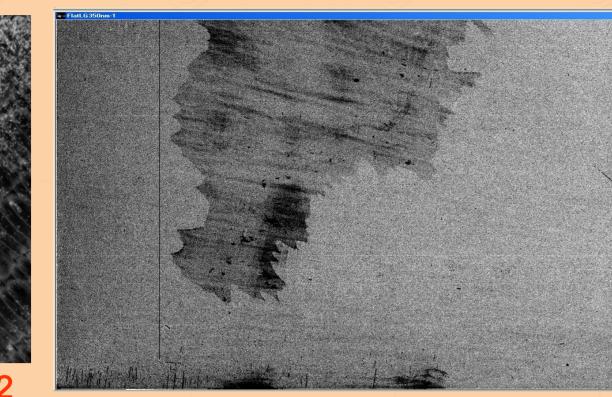
by gas, radiative and thermal treatment

Sebastian Deiries, Mark Downing, Dietrich Baade **European Organisation for Astronomical Research in the Southern Hemisphere**

Ink stain removal

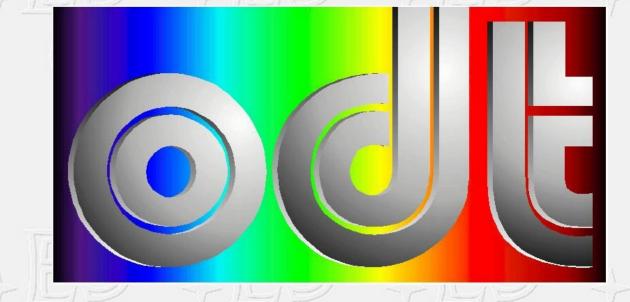
Before treatment





Summary:

A combination of oxygen (O2) soaking, UV flooding and baking permits the removal of "ink-stain" patterns of reduced UV and blue sensitivity observed in MIT/LL CCDs flat fields. With further optimization of the recipe, significantly improved quantum efficiency (QE) of e2v CCD44-82 CCDs was also achieved, especially at blue wavelengths. Examples of QE curves and CCD flat fields before and after the sensitization are shown, and crude estimates of the long-term stability of the results are given. A possible explanation is that water vapor contaminates the surface of the CCD and deteriorates the efficiency of



Optical Detector Team

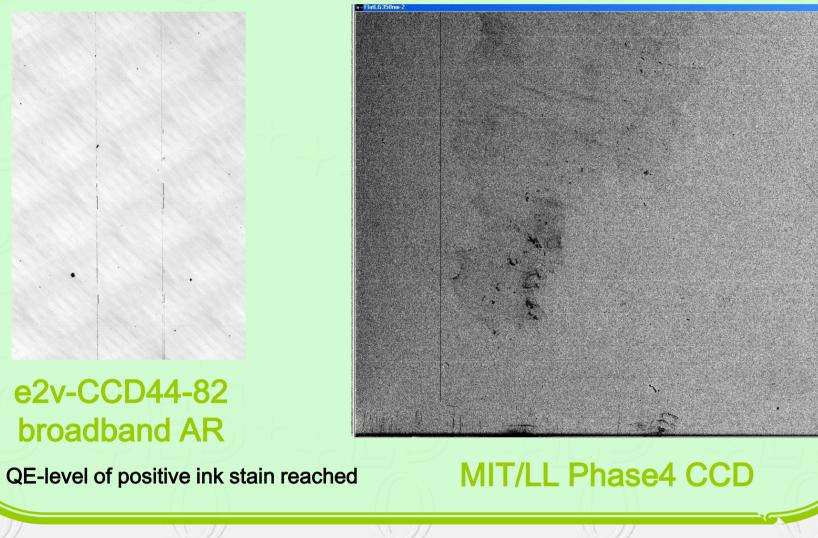
UV flooding

broadband AR

broadband AR

MIT/LL Phase4 CCD

After UV-/O2-treatment



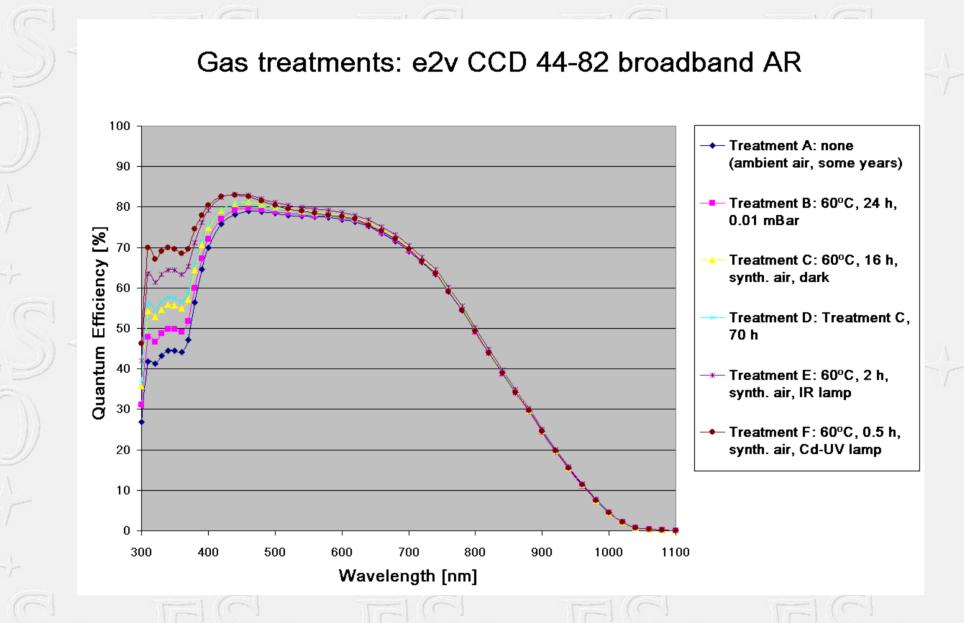
Original recipe from Mingzhi Wei

"Soaking the CCDs in O2 at the same time heating them by a tungsten lamp and then quickly cool them. It works if the CCD is heated in the air: Maybe O2 from the air is sufficient."

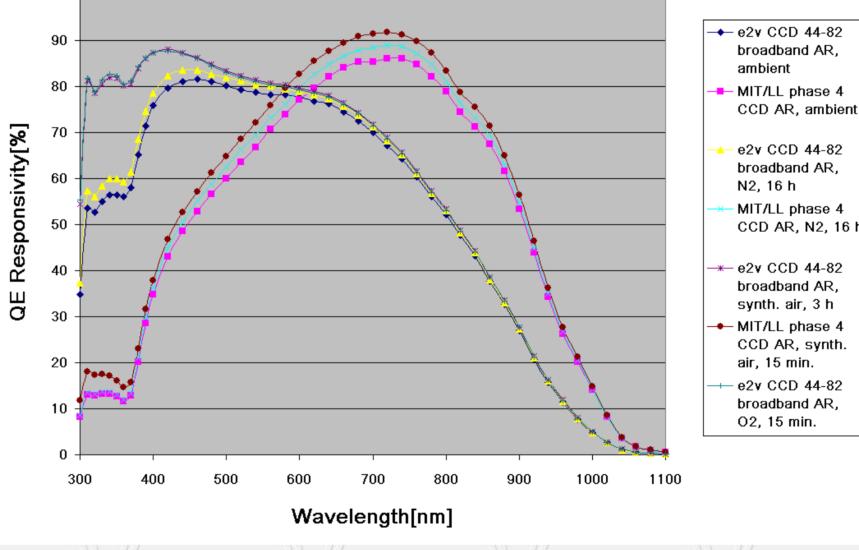
(Personal communication from April 10th, 2004)

the AR coating but is removed by the described procedure. An overview of the instrumental setup, the required materials, and precautionary measures is provided.

Results



While the QE of e2v CCDs could be improved in the UV, blue and green, the QE improvement of MIT/LL CCD is only marginal:



← e2v CCD 44-82 - MIT/LL phase 4 CCD AR, ambient

Explanation: Contamination by H₂O or H⁺ molecules?

UV treatment at ODT test bench with cadmium

lamp

Further developed recipe from ODT

Pumping the cryostat with regeneration of sorption pump Flushing of cryostat 2 - 3 times with dry synthetic air to 0.8 Bar: Over-pressure valve needed to prevent blowing out the window! > Pumping of cryostat and heating of CCD to 60 degrees centigrade Filling of warm cryostat with synthetic air (or pure O2) to 0.8 Bar Flooding of CCD through quartz window with UV-lamp for 5 minutes Pumping and cooling of cryostat within 6 hours Precautions: The use of pure O2 is dangerous and may corrode bond wires of CCDs and the cryostat. Do not blow out the cryostat window.

Experimental setup

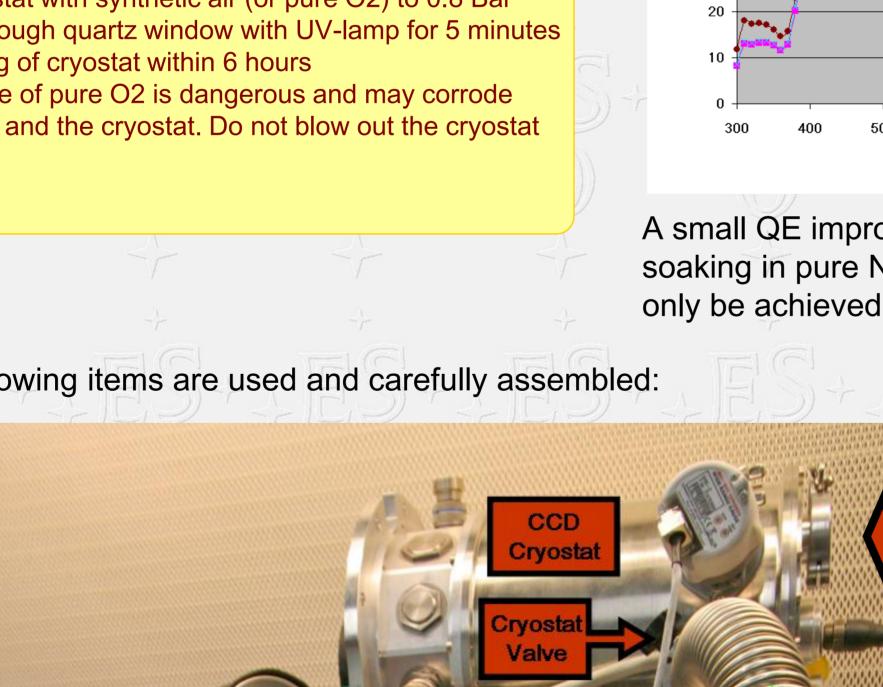
For the experimental set-up the following items are used and carefully assembled:

UV-Lamp

Gas

Dry vacuum pump up to 10⁻⁵ mBar Safety over-pressure valve: 0.1 Bar > Dry synth. air gas cylinder with pressure reducer 0-5 Bar Gas pressure manometer 0 - 1000 mBar > Oil-free KF fittings, valves and flexible pipes

UV-lamp (mercury discharge or cadmium spectral lamp)



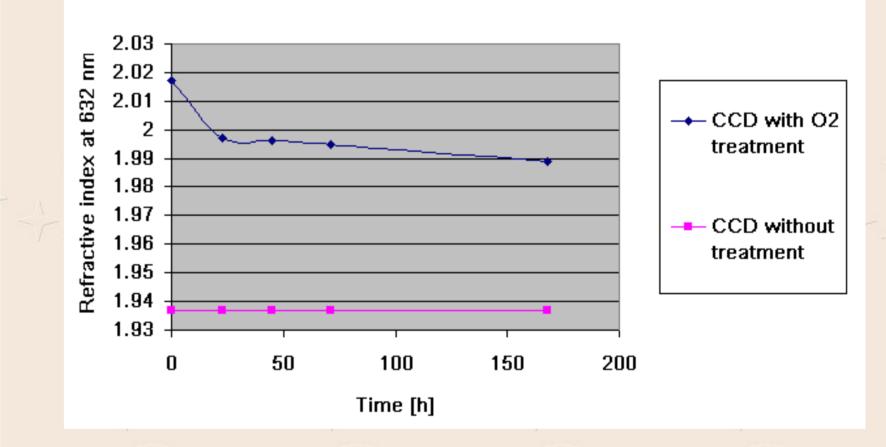
To Cryostat

A small QE improvement at e2v CCDs is reached by heating and soaking in pure N2 gas. An improvement of up to 60 % in the UV can only be achieved by means of soaking in synthetic air or pure O2.



CCD detector warmed up to 60 degrees centigrade

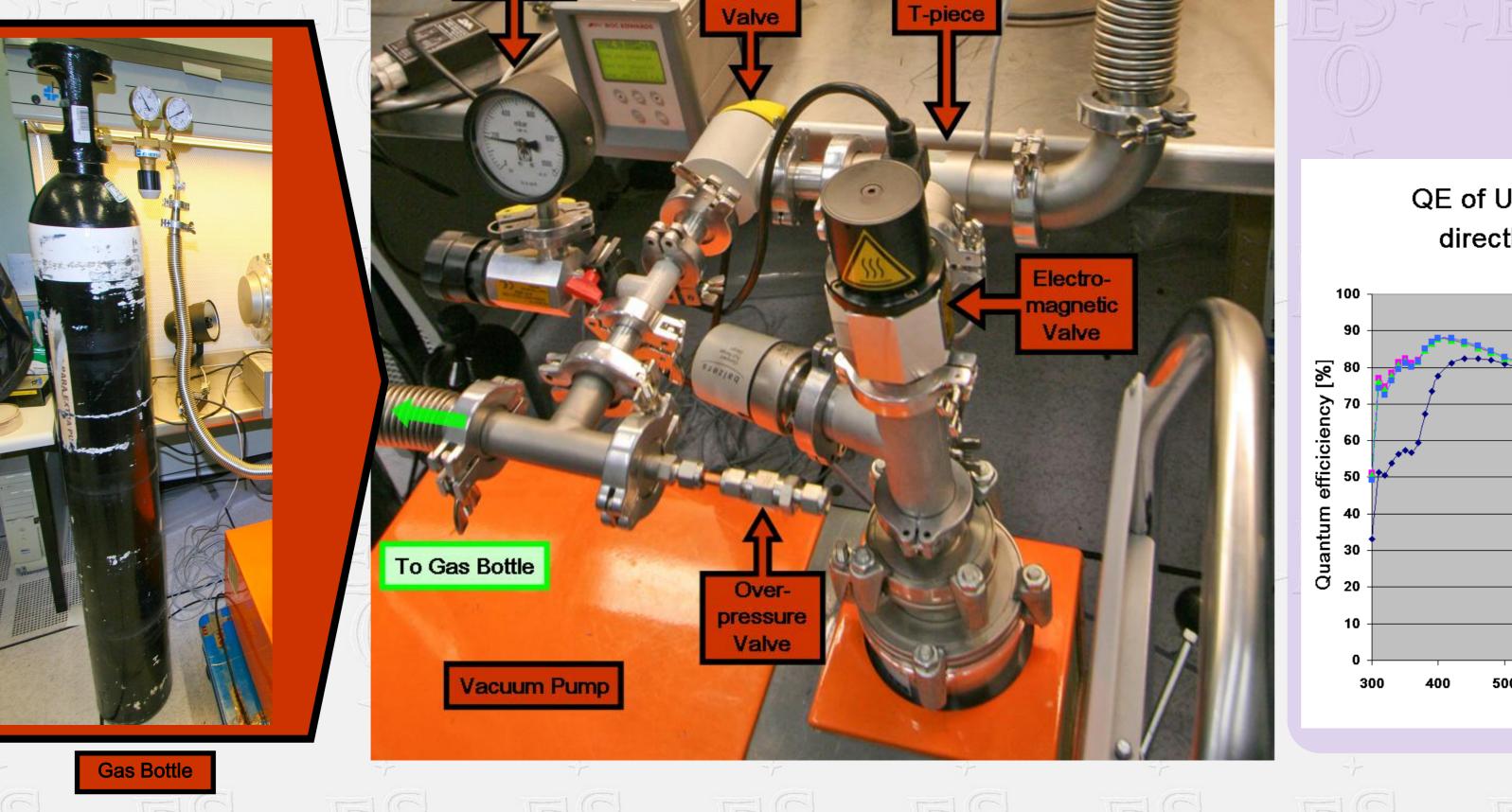
Refractive index measurement of QE improved e2v CCD 44-82 broadband AR



The refractive index of the AR coating of a CCD treated as described above is higher than the one of an untreated CCD but slowly decreases with time (measurements by SenTech, Berlin). One possible explanation is that, with time and under atmospheric conditions, the AR coating adsorbs H_2O and/or H^+ molecules, which change the refractive index. Since the AR coating is most important at UV and blue wavelength, the observed effect is strongest there. This would be consistent with occasional reports that the UV efficiency of CCDs improves after years of operation under high vacuum, when H_2O / H^+ might be desorbed.

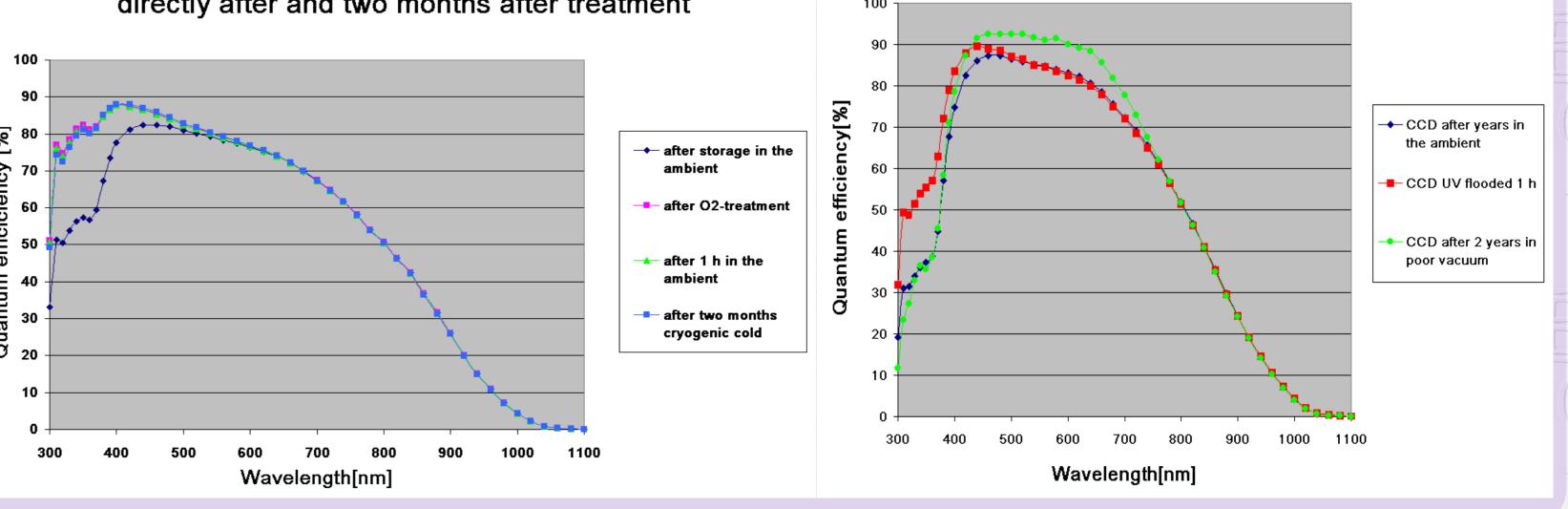
Vacuum + cryo-temperature \Rightarrow ~ 1-2 years 1 mBar $\Rightarrow \sim 2$ months Ambient air $\Rightarrow \sim 1$ week

Long-term stability



QE of UVES blue e2v CCD 44-82 UV AR before, directly after and two months after treatment

Gas treatment and long-term stability of e2v CCD 44-82 broadband AR



Detectors for Astronomy, 12 - 16 October 2009, ESO Garching